# NSN 5961-01-037-8874

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# Inclosure Material:

Metal

**Overall Length:** 

1.252 inches

# Terminal Length:

0.360 inches

# **Overall Height:**

0.340 inches

# Overall Width:

0.700 inches

# Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

То-66

#### Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Unthreaded hole and terminal

### **Features Provided:**

Hermetically sealed case

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

-50.0 collector to base voltage/static/emitter open and -50.0 collector to emitter voltage, dc with specified circuit between base and emitter

and -45.0 collector to emitter reverse voltage and -40.0 collector to emitter voltage/static/base open

#### **Current Rating Per Characteristic:**

-6.00 amperes source cutoff current and -2.00 amperes source cutoff current

#### Power Rating Per Characteristic:

40.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: pnp

#### **Terminal Type And Quantity:**

2 pin and 1 case

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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